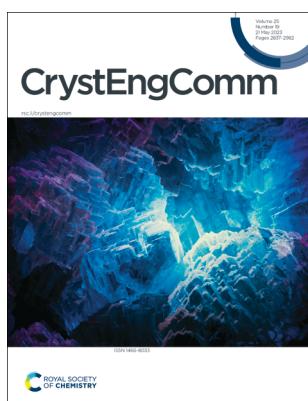


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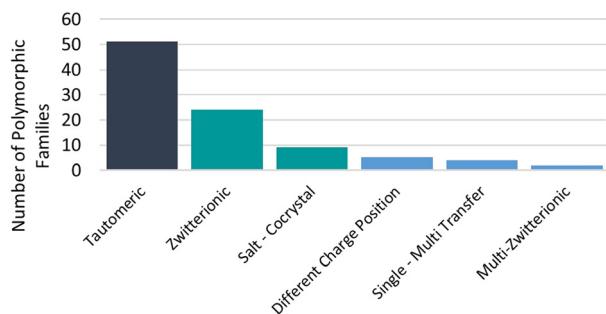
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A to Z of polymorphs related by proton transfer

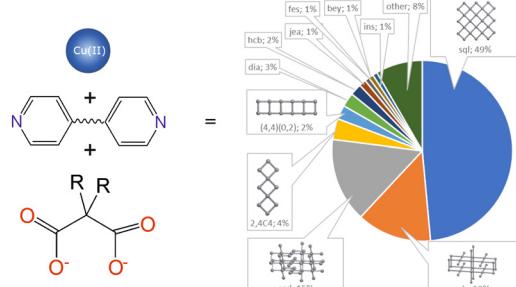
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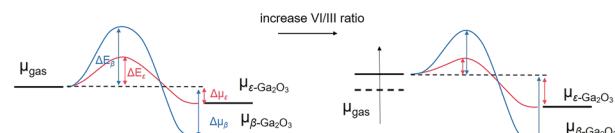


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Metal-organic chemical vapor deposition of ϵ -Ga₂O₃ thin film using N₂O as a precursor

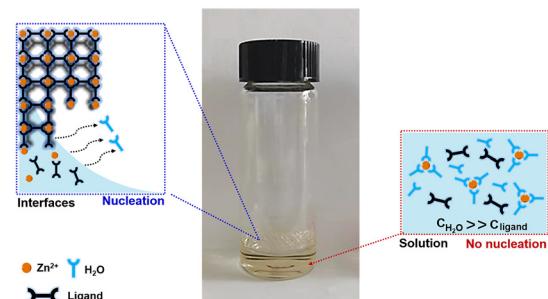
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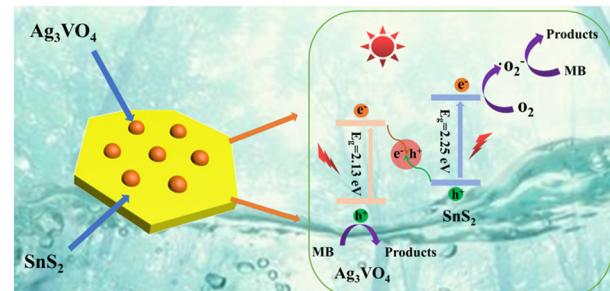
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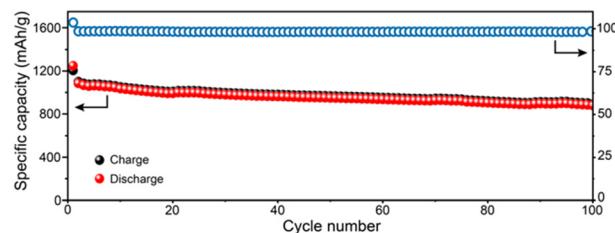
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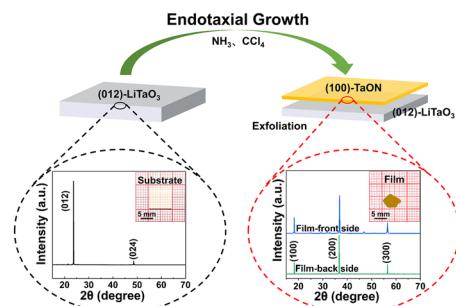
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Chengyao Zhu, Jin Wang, Guiying Xu, Xuan Du, Chuxin Chen, Xiangwei Yang, Chongjun Bao and Guo Gao*



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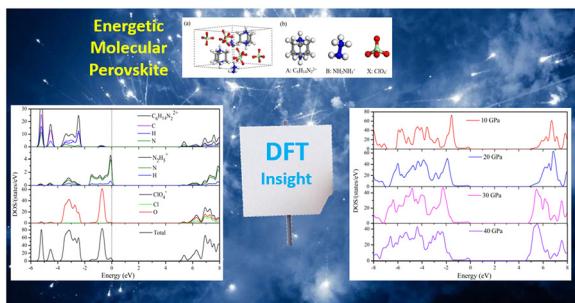
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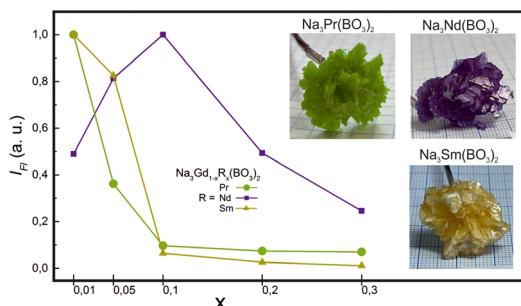
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Qiaoli Li, Shenshen Li and Jijun Xiao*

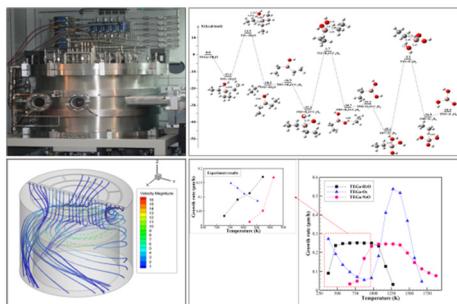
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Jie Wang, Tie-cheng Luo, Zhuo Yang, Yi-cong He, Jian Li and Gang Wang*

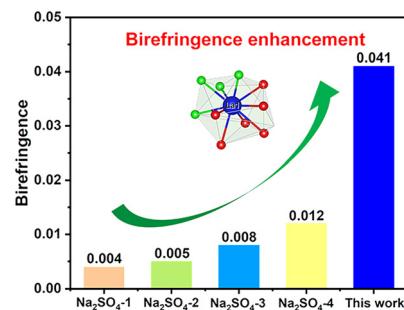


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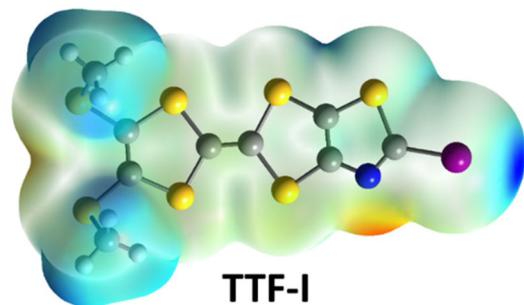
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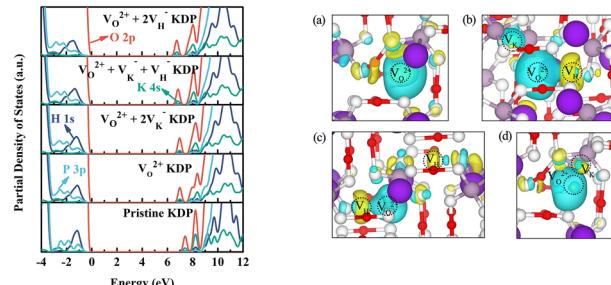
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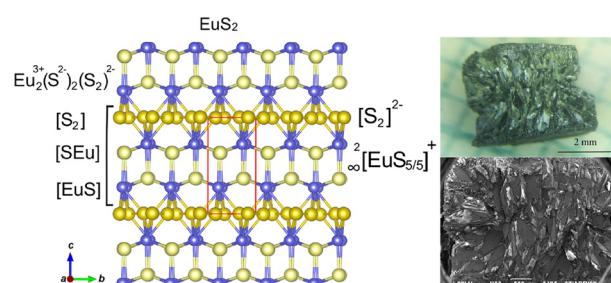
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CORRECTION

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Correction: High-pressure and low-temperature structural study of claudetite I, a monoclinic layered As_2O_3 polymorph

Piotr A. Guńka,* Michael Hanfland, Yu-Sheng Chen and Janusz Zachara

